

November 2005



LM109JAN 5-Volt Regulator General Description

The LM109 series are complete 5V regulators fabricated on a single silicon chip. They are designed for local regulation on digital logic cards, eliminating the distribution problems association with single-point regulation. The devices are available in two standard transistor packages. In the solidkovar TO-5 header, it can deliver output currents in excess of 200 mA, if adequate heat sinking is provided. With the TO-3 power package, the available output current is greater than 1A.

The regulators are essentially blowout proof. Current limiting is included to limit the peak output current to a safe value. In addition, thermal shutdown is provided to keep the IC from overheating. If internal dissipation becomes too great, the regulator will shut down to prevent excessive heating.

Considerable effort was expended to make these devices easy to use and to minimize the number of external components. It is not necessary to bypass the output, although this does improve transient response somewhat. Input bypassing is needed, however, if the regulator is located very far from the filter capacitor of the power supply. Stability is also achieved by methods that provide very good rejection of load or line transients as are usually seen with TTL logic.

Although designed primarily as a fixed-voltage regulator, the output of the LM109 series can be set to voltages above 5V, as shown. It is also possible to use the circuits as the control element in precision regulators, taking advantage of the good current-handling capability and the thermal overload protection.

Features

- Specified to be compatible, worst case, with TTL and DTL
- Output current in excess of 1A
- Internal thermal overload protection
- No external components required

Ordering Information

NS Part Number	JAN Part Number	NS Package Number	Package Description
JL109BXA	JM38510/10701BXA	H03A	3LD Metal Can
JL109BYA	JM38510/10701BYA	K02C	2LD T0-3 Metal Can

Connection Diagrams

Metal Can Packages





See NS Package Number K02C Bottom View

Schematic Diagram

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Absolute Maximum Ratings (Note 1)

	051/
input voitage	35V
Power Dissipation	Internally Limited
Operating Ambient Temperature Range	$-55^{\circ}C \le TA \le +150^{\circ}C$
Storage Temperature Range	$-65^{\circ}C \le TA \le +150^{\circ}C$
Maximum Junction Temperature	150°C
Thermal Resistance	
θ_{JA}	
H-Pkg (Still Air)	190°C/W
H-Pkg (500LF/Min Air flow)	69°C/W
K-Pkg (Still Air)	39°C/W
K-Pkg (500LF/Min Air flow)	TBD
θ _{JC}	
H-Pkg	25°C/W
K-Pkg	3°C/W
Lead Temperature (Soldering, 10 sec.)	300°C
ESD Tolerance (Note 9)	4000V

Quality Conformance Inspection Mil-Std-883, Method 5005 - Group A

Subgroup	Description	Temp °C
1	Static tests at	25
2	Static tests at	125
3	Static tests at	-55
4	Dynamic tests at	25
5	Dynamic tests at	125
6	Dynamic tests at	-55
7	Functional tests at	25
8A	Functional tests at	125
8B	Functional tests at	-55
9	Switching tests at	25
10	Switching tests at	125
11	Switching tests at	-55
12	Settling time at	25
13	Settling time at	125
14	Settling time at	-55

JL109H Electrical Characteristics DC Parameters

Symbol	Parameter	neter Conditions Notes		Min	Max	Unit	Sub- groups
Vo	Output Voltage	$V_{I} = 7V, I_{L} = -5mA$		4.7	5.4	V	1, 2, 3
		$V_{I} = 7V, I_{L} = -0.5A$	(Note 3)	4.7	5.4	V	1, 2, 3
		$V_{I} = 9V, I_{L} = -0.5A$		4.7	5.4	V	1, 2, 3
		$V_{I} = 25V, I_{L} = -5mA$		4.7	5.4	V	1, 2, 3
		$V_{I} = 25V, I_{L} = -100mA$		4.7	5.4	V	1, 2, 3
V _{RLine}	Line Regulation	$7V \le V_I \le 25V, I_L = -5mA$		-50	50	mV	1
				-100	100	mV	2, 3
V _{RLoad}	Load Regulation	$V_{I} = 10V, -0.5A \le I_{L} \le -5mA$		-100	100	mV	1, 2, 3
I _{SCD}	Standby Current Drain	$V_{I} = 7V, I_{L} = -5mA$		-10	0.5	mA	1, 2, 3
		$V_{I} = 25V, I_{L} = -5mA$		-10	0.5	mA	1, 2, 3
∆I _{SCD} (Line)	Standby Current Drain vs Line Voltage	$7V \le V_1 \le 25V, I_L = -5mA$		-0.5	0.5	mA	1, 2, 3
∆l _{SCD} (Load)	Standby Current Drain vs Load Current	$V_I = 10V$, $-0.5A \le I_L \le -5mA$		-0.8	0.8	mA	1, 2, 3
l _{os}	Output Short Circuit Current	V ₁ = 35V		-2.0	0.01	А	1, 2, 3
V _{Start}	Minimum Start Up Input Voltage	$R_{L} = 25\Omega \pm 5\%$	(Note 8)		9.0	V	1, 2, 3
ΔV _O / ΔT	Average Temperature Coefficient of Output Voltage	$V_{I} = 7V, I_{L} = -5mA$	(Note 4)	-2.0	2.0	mV/°C	8A, 8B

AC Parameters

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
No	Output Noise Voltage	$V_{I} = 10V, I_{L} = -50mA$			125	μV_{RMS}	7
ΔV_{O} / ΔV_{I}	Line Transient Response	$V_{I} = 10V, V_{Pulse} = 3V,$	(Note 5)		45	mV	7
		$I_{L} = -5mA$					
$\Delta V_{O} / \Delta I_{L}$	Load Transient Response	$V_{I} = 10V, I_{L} = -50mA,$	(Note 7)		400	mV	7
		$\Delta I_{L} = -200 \text{mA}$					
$\Delta V_{I} / \Delta V_{O}$	Ripple Rejection	$V_{I} = 10V, I_{L} = -125mA,$		60		dB	4
		$e_I = 1V_{RMS}$ at $f = 2400Hz$					

DC Drift Parameters

Delta calculations performed on JAN S devices at group B, Subgroup 5, only.

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
Vo	Output Voltage	$V_{I} = 7V, I_{L} = -5mA$		-0.025	0.025	V	1
		$V_{I} = 7V, I_{L} = -0.5A$		-0.025	0.025	V	1
		$V_{I} = 9V, I_{L} = -0.5A$		-0.025	0.025	V	1
		$V_{I} = 25V, I_{L} = -5mA$		-0.025	0.025	V	1
		$V_{I} = 25V, I_{L} = -100mA$		-0.025	0.025	V	1
V _{RLine}	Line Regulation	$7V \le V_I \le 25V, \ I_L = -5mA$		-10	10	mV	1
V _{RLoad}	Load Regulation	$V_{I}=10V,\ \text{-}0.5A\leq I_{L}\leq\text{-}5mA$		-10	10	mV	1
I _{SCD}		$V_{I} = 7V, I_{L} = -5mA$		-1.0	1.0	mA	1
		$V_{I} = 25V, I_{L} = -5mA$		-1.0	1.0	mA	1

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JL109K Electrical Characteristics DC Parameters

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
Vo	Output Voltage	$V_{I} = 7V, I_{L} = -5mA$		4.7	5.4	V	1, 2, 3
		$V_{I} = 7V, I_{L} = -1.5A$	(Note 3)	4.7	5.4	V	1, 2, 3
		$V_{I} = 18V, I_{L} = -1.5A$		4.7	5.4	V	1, 2, 3
		$V_{I} = 25V, I_{L} = -5mA$		4.7	5.4	V	1, 2, 3
		$V_{I} = 25V, I_{L} = -1A$		4.7	5.4	V	1, 2, 3
V _{RLine}	Line Regulation	$7V \le V_I \le 25V, I_L = -5mA$		-50	50	mV	1
				-100	100	mV	2, 3
V _{RLoad}	Load Regulation	$V_{I} = 10V, -1.5A \le I_{L} \le -5mA$		-100	100	mV	1, 2, 3
I _{SCD}	Standby Current Drain	$7V \le V_I \le 25V, I_L = -5mA$		-10	0.5	mA	1, 2, 3
∆l _{SCD} (Line)	Standby Current Drain vs Line Voltage	$7V \le V_1 \le 25V, I_L = -5mA$		-0.5	0.5	mA	1, 2, 3
∆l _{SCD} (Load)	Standby Current Drain vs Load Current	$V_I = 10V, -1.5A \le I_L \le -5mA$		-0.8	0.8	mA	1, 2, 3
l _{os}	Output Short Circuit Current	V ₁ = 35V		-2.8	0.01	А	1, 2, 3
V _{Start}	Minimum Start Up Input Voltage	$R_{L} = 5\Omega \pm 5\%$	(Note 8)		9.0	V	1, 2, 3
ΔV _O / ΔT	Average Temperature Coefficient of Output Voltage	$V_{I} = 7V, I_{L} = -5mA$	(Note 4)	-2.0	2.0	mV/°C	8A, 8B

AC Parameters

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
No	Output Noise Voltage	$V_{I} = 10V, I_{L} = -100mA$			125	μV_{RMS}	7
ΔV_{O} / ΔV_{I}	Line Transient Response	$V_I = 10V, V_{Pulse} = 3V,$	(Note 5)		45	mV	7
		I _L = -5mA					
ΔV_{O} / ΔI_{L}	Load Transient Response	$V_{I} = 10V, I_{L} = -100mA,$	(Note 6)		800	mV	7
		$\Delta I_{L} = -400 \text{mA}$					
$\Delta V_{I} / \Delta V_{O}$	Ripple Rejection	$V_{I} = 10V, I_{L} = -350mA,$		60		dB	4
		$e_I = 1V_{RMS}$ at $f = 2400Hz$					

DC Drift Parameters

Delta calculations performed on JAN S devices at group B, Subgroup 5, only.

Symbol	Parameter	Conditions	Notes	Min	Мах	Unit	Sub- groups
Vo	Output Voltage	$V_{I} = 7V, I_{L} = -5mA$		-0.025	0.025	V	1
		$V_{I} = 7V, I_{L} = -1.5A$		-0.025	0.025	V	1
		$V_{I} = 18V, I_{L} = -1.5A$		-0.025	0.025	V	1
		$V_{I} = 25V, I_{L} = -5mA$		-0.025	0.025	V	1
		$V_{I} = 25V, I_{L} = -1A$		-0.025	0.025	V	1
V _{RLine}	Line Regulation	$7V \leq V_{I} \leq 25V, \ I_{L} = -5mA$		-10	10	mV	1
V _{RLoad}	Load Regulation	$V_{I}=10V,\ \text{-}1.5A\leq I_{L}\leq\text{-}5mA$		-10	10	mV	1
I _{SCD}	Standby Current Drain	$7V \leq V_I \leq 25V, I_L = -5mA$		-1.0	1.0	mA	1

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: This test is performed by shifting the input voltage in 50mV increments until output reaches 4.706V.

Note 3: $V_1 = 8V$ at $-55^{\circ}C$.

Note 4: Calculated parameter.

Note 5: Slash Sheet limit of 15 mV/V is equivalent to 45mV

Note 6: Slash Sheet limit of 2mV/mA is equivalent to 800mV

Note 7: Slash Sheet limit of 2mV/mA is equivalent to 400mV

Note 8: Parameter tested go-no-go, only.

Note 9: Human body model, $1.5k\Omega$ in series with 100_PF .

Application Hints

- Bypass the input of the LM109 to ground with ≥ 0.2 µF ceramic or solid tantalum capacitor if main filter capacitor is more than 4 inches away.
- Avoid insertion of regulator into "live" socket if input voltage is greater than 10V. The output will rise to within 2V of the unregulated input if the ground pin does not make contact, possibly damaging the load. The LM109 may also be damaged if a large output capacitor is charged up, then discharged through the internal clamp zener when the ground pin makes contact.
- 3. The output clamp zener is designed to absorb transients only. It will not clamp the output effectively if a failure occurs in the internal power transistor structure. Zener dynamic impedance is $\approx 4\Omega$. Continuous RMS current into the zener should not exceed 0.5A.
- 4. Paralleling of LM109s for higher output current is not recommended. Current sharing will be almost nonexistent, leading to a current limit mode operation for devices with the highest initial output voltage. The current limit devices may also heat up to the thermal shutdown point (≈ 175°C). Long term reliability cannot be guaranteed under these conditions.
- 5. **Preventing latchoff** for loads connected to negative voltage:

If the output of the LM109 is pulled negative by a high current supply so that the output pin is more than 0.5V negative with respect to the ground pin, the LM109 can latch off. This can be prevented by clamping the ground pin to the output pin with a germanium or Schottky diode as shown. A silicon diode (1N4001) at the output is also needed to keep the positive output from being pulled too far negative. The 10 Ω resistor will raise +V_{OUT} by \approx 0.05V.



Crowbar Overvoltage Protection



20154908





*Zener is internal to LM109.

**Q1 must be able to withstand 7A continuous current if fusing is not used at regulator input. LM109 bond wires will fuse at currents above 7A. †Q2 is selected for surge capability. Consideration must be given to filter capacitor size, transformer impedance, and fuse blowing time. ††Trip point is \approx 7.5V.



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Typical Performance Characteristics (Continued)











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Typical Applications (Continued)







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*Determines output current. If wirewound resistor is used, bypass with 0.1 $\mu\text{F}.$

Revision History								
Date Released	Revision	Section	Originator	Changes				
11/08/05	A	New release to corporate format	L. Lytle	2 MDS datasheets converted into one datasheet in the corporate format. MJLM109-K Rev 0BL & MJLM109-H Rev 0AL will be archived.				

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Notes

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